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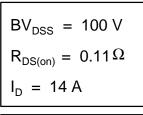
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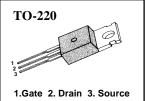
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Advanced Power MOSFET

FEATURES

- Avalanche Rugged Technology
- Rugged Gate Oxide Technology
- Lower Input Capacitance
- Improved Gate Charge
- Extended Safe Operating Area
- 175°C Operating Temperature
- Lower Leakage Current : 10 µA (Max.) @ V_{DS} = 100V
- Lower $R_{DS(ON)}$: 0.092 $\Omega(Typ.)$





Absolute Maximum Ratings

Symbol	Characteristic	Value	Units		
V _{DSS}	Drain-to-Source Voltage	100	V		
	Continuous Drain Current (T _C =25°C)		14		
۱ _D	Continuous Drain Current (T _c =100°C	9.9	A		
I _{DM}	Drain Current-Pulsed	0	56	А	
V _{GS}	Gate-to-Source Voltage	± 20	V		
E _{AS}	Single Pulsed Avalanche Energy	261	mJ		
I _{AR}	Avalanche Current	0	14	А	
E _{AR}	Repetitive Avalanche Energy	0	5.5	mJ	
dv/dt	Peak Diode Recovery dv/dt	3	6.5	V/ns	
Б	Total Power Dissipation $(T_c=25^{\circ}C)$		55	W	
P _D	Linear Derating Factor	0.36	W/°C		
	Operating Junction and				
T _J , T _{STG}	Storage Temperature Range	- 55 to +175	°C		
	Maximum Lead Temp. for Soldering		200		
TL	Purposes, 1/8" from case for 5-second	nds	300		

Thermal Resistance

Symbol	Characteristic	Тур.	Max.	Units
R _{θJC}	Junction-to-Case		2.74	
R _{θCS}	R _{ecs} Case-to-Sink			°C/W
R _{θJA}	Junction-to-Ambient		62.5	



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Symbol	Characteristic	Min.	Тур.	Max.	Units	Test Condition
BV_{DSS}	Drain-Source Breakdown Voltage	100			V	V _{GS} =0V,I _D =250
$\Delta \text{BV} / \Delta \text{T}_{\text{J}}$	Breakdown Voltage Temp. Coeff.		0.11		V/ °C	I _D =250 μΑ See Fig 7
V _{GS(th)}	Gate Threshold Voltage	2.0		4.0	V	V _{DS} =5V,I _D =250μA
_	Gate-Source Leakage, Forward			100	n۸	V _{GS} =20V
I _{GSS}	Gate-Source Leakage, Reverse			-100	0 nA	V _{GS} =-20V
I				10		V _{DS} =100V
IDSS	Drain-to-Source Leakage Current			100	μA	V _{DS} =80V,T _C =150°C
D	Static Drain-Source					V 40V/L 70 Ø
$R_{DS(on)}$	^{on)} On-State Resistance	0.11	Ω	V_{GS} =10V,I _D =7A (4)		
g _{fs}	Forward Transconductance		10.25		Ω	V _{DS} =40V,I _D =7A ④
C _{iss}	Input Capacitance		610	790		
C _{oss}	Output Capacitance		150	175	рF	V _{GS} =0V,V _{DS} =25V,f =1MHz
C _{rss}	Reverse Transfer Capacitance		62	72		See Fig 5
t _{d(on)}	Turn-On Delay Time		13	40		
t _r	Rise Time		14	40		V _{DD} =50V,I _D =14A,
t _{d(off)}	Turn-Off Delay Time		55	110	ns	$R_{G}=12\Omega$
t _f	Fall Time		36	80		See Fig 13 ④⑤
Q_{g}	Total Gate Charge		27	36		V _{DS} =80V,V _{GS} =10V,
Q_{gs}	Gate-Source Charge		4.5		nC	I _D =14A
Q_{gd}	Gate-Drain("Miller") Charge		12.8			See Fig 6 & Fig 12 ④⑤

Electrical Characteristics ($T_C=25$ °C unless otherwise specified)

Source-Drain Diode Ratings and Characteristics

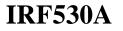
Symbol	Characteristic		Min.	Тур.	Max.	Units	Test Condition
ا _s	Continuous Source Current				14	А	Integral reverse pn-diode
I _{SM}	Pulsed-Source Current (0			56	A	in the MOSFET
V _{SD}	Diode Forward Voltage	€			1.5	V	T _J =25℃,I _S =14A,V _{GS} =0V
t _{rr}	Reverse Recovery Time			109		ns	T _J =25°C,I _F =14A
Q _{rr}	Reverse Recovery Charge			0.41		¥ìC	di _F /dt=100A/µs ④

Notes;

- ① Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature
- 2 L=2mH, I_{AS}=14A, V_{DD}=25V, R_G=27 Ω , Starting T_J=25 °C
- $(\textbf{3} | I_{SD} \leq 14 \text{A}, \text{ di/dt} \leq 350 \text{A}/\mu\text{s}, \text{V}_{DD} \leq \text{BV}_{DSS}, \text{ Starting } \text{T}_{\text{J}} = 25^{\circ}\text{C}$
- 0 Pulse Test : Pulse Width = 250 µs, Duty Cycle $\leq 2\%$
- **(5)** Essentially Independent of Operating Temperature

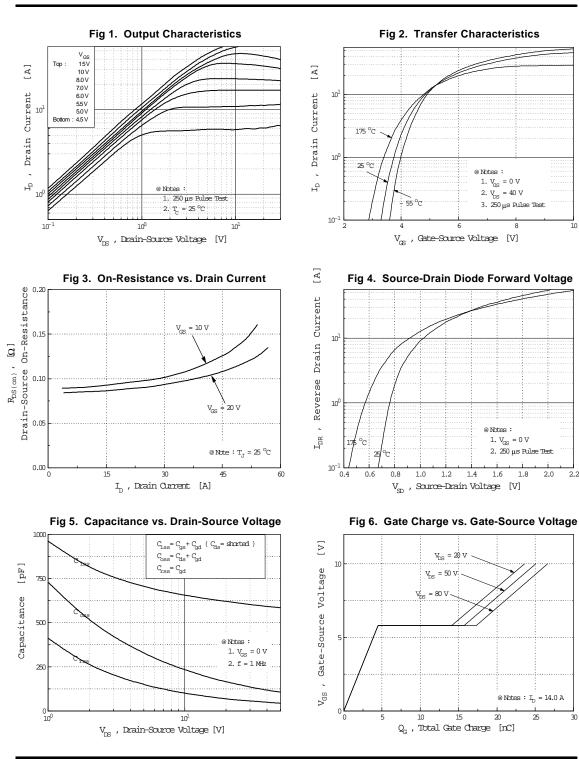


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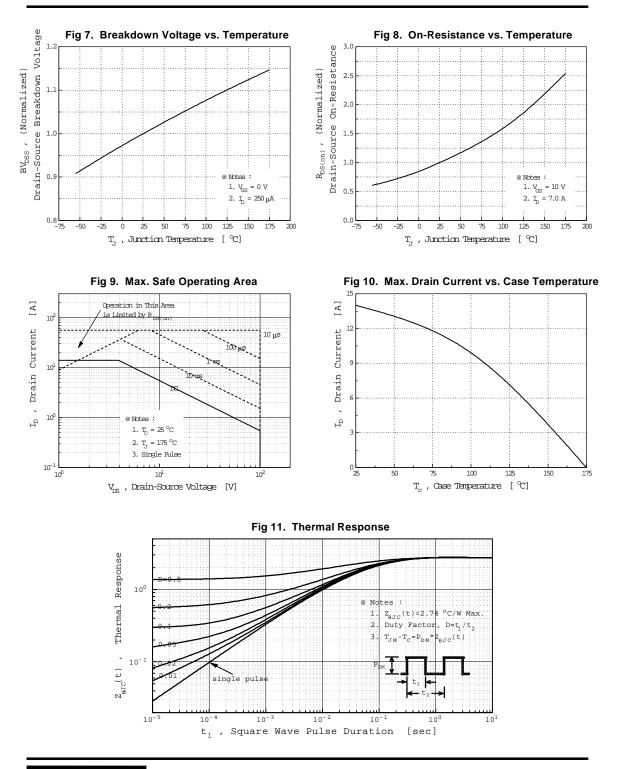
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FAIRCHIL SEMICONDUCTOR

IRF530A

N-CHANNEL POWER MOSFET





SEMICONDUCTOR

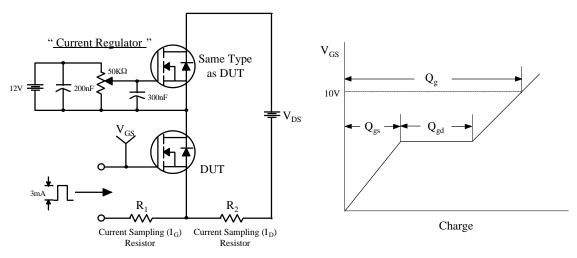


Fig 12. Gate Charge Test Circuit & Waveform



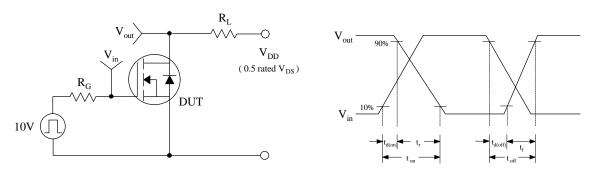
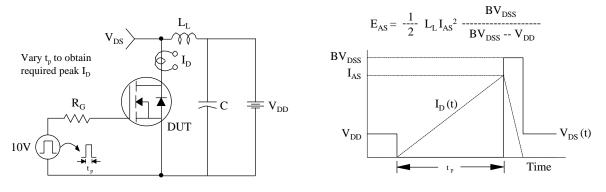


Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms





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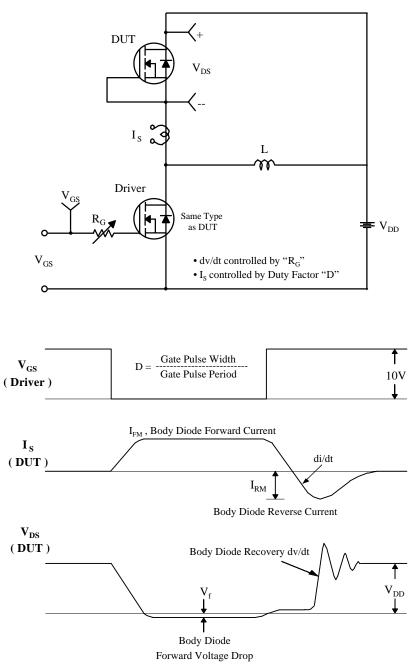


Fig 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms



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